Unit in mm

TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

TLP176G

Modems In PC Modem-Fax Cards

Telecommunictions

The TOSHIBA TLP176G consists of gallium arsenide infared emitting diode optically coupled to a photo–MOS FET in a SOP, which is suitable for surface mount assembly.

The TLP176G is suitable for the modem applications which require space savings.

• Peak off-state voltage: 350V (min)

• Trigger LED current: 3mA (max)

• On–state resistance: 35Ω (max)

• Isolation voltage: 1500Vrms (min)

• UL recognized: UL1577, file No. E67349

• BSI approved

: BS EN60065: 1994,certificate No.8273 BS EN60950: 1992,certificate No.8274

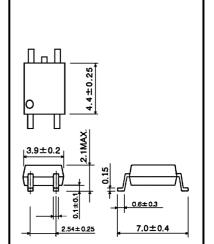
• SEMKO approved: SS EN60065

SS EN60950

• Option(V4)type

TUV approved: DIN VDE0884 / 06.92,

Certificate No.R9850580

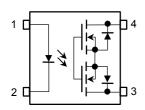


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TOSHIBA

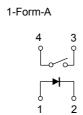
Weight: 0.1 g

JEDEC

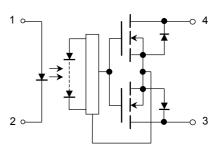
Pin Configuration (top view)



: Anode
 : Cathode
 : Drain
 : Drain



Schematic



Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	ΙF	50	mA
	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.5	mA / °C
LED	Pulse forward current (100µs pulse,100pps)	I _{FP}	1	Α
	Reverse voltage	V_{R}	5	V
	Junction temperature	Tj	125	°C
	Off-state output terminal voltage	V _{OFF}	350	V
Detector	On-state current	I _{ON}	120	mA
Dete	On–state current derating (Ta ≥ 25°C)	Δl _{ON} / °C	-1.2	mA / °C
	Junction temperature	Tj	125	°C
Total power dissipation		PT	350	mW
Total power dissupation derating(Ta ≥ 25°C)		ΔPT / °C	-0.35	mW / °C
Storage temperature range		T _{stg}	-55~125	°C
Operating temperature range		T _{opr}	-40~85	°C
Lead	Lead soldering temperature(10 s)		260	°C
Isolation voltage (AC,1 min., R.H.≤ 60%) (Note 1)		BVS	1500	Vrms

(Note 1): Device considered a two-terminal device: Pin 1 and 2 shorted together and pin 3 and 4 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{DD}	_	_	280	V
Forward current	I _F	5	7.5	25	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V_{F}	I _F = 10mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5V	_	_	10	μΑ
	Capacitance	C _T	V = 0,f = 1MHz	_	30	-	pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 350V	_	_	1	μΑ
	Capacitance	C _{OFF}	V = 0,f = 1MHz	_	40	-	pF

Coupled Electrical Characteristics (Ta = 25°C)

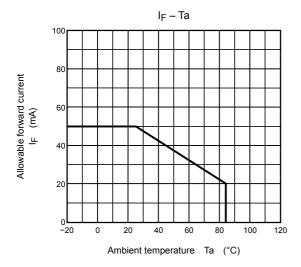
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	I _{ON} = 120mA	_	1	3	mA
On-state resistance	R _{ON}	I _{ON} = 120mA,I _F = 5mA	_	22	35	Ω

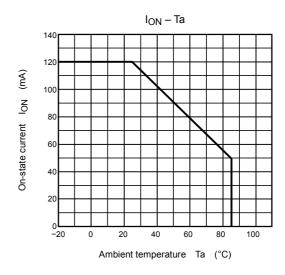
Isolation Characteristics (Ta = 25°C)

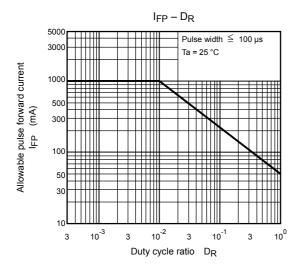
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0,f = 1MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500V,R.H ≤ 60%	5×10 ¹⁰	10 ¹⁴		Ω
		AC, 1minute	1500	_		Vrms
Isolation voltage	BV_S	AC, 1second (in oil)	_	3000	-	VIIIIS
		DC, 1minute (in oil)	_	3000		Vdc

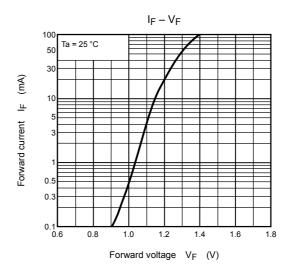
Switching Characteristics (Ta = 25°C)

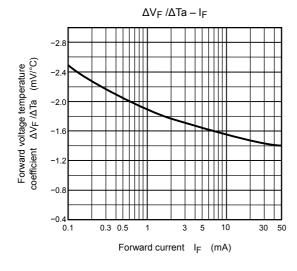
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t _{ON}	R _L = 200Ω	_	0.3	1	ms
Turn-off time	t _{OFF}	V_{CC} = 20V, I_F = 5mA	_	0.1	1	1113

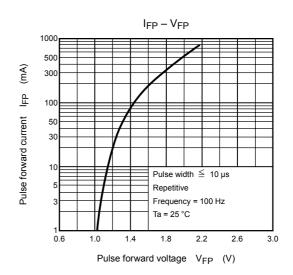


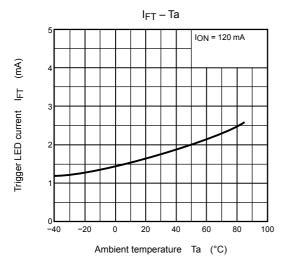


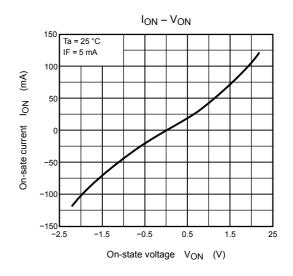


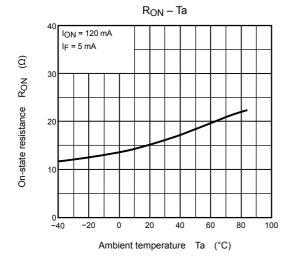


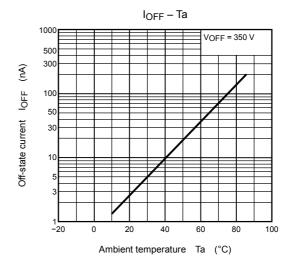


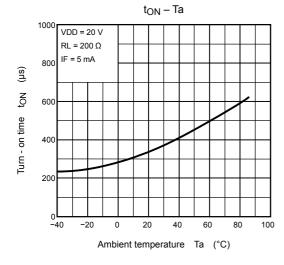


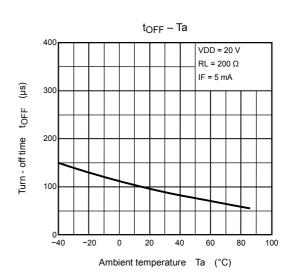




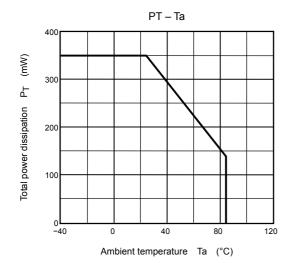








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